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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR **2SK4147**

SWITCHING N-CHANNEL MOSFET

DESCRIPTION

The 2SK4147 is a switching element that is most suitable for use in DC-DC converter whose DC input voltage is 24 to 48 V.

Having low on-resistance, excelling in the switching characteristics, and providing the small surface mounting outline, the 2SK4147 is ideal for use in high-speed switching of the devices on which space-saving and automation of mounting are promoted.

FEATURES

- Low input capacitance
 C_{iss} = 120 pF TYP.
- · Low on-state resistance

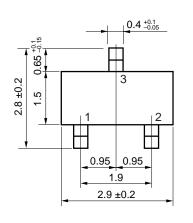
 $R_{DS(on)1} = 4.5 \Omega MAX. (V_{GS} = 10 V, I_{D} = 0.25 A)$

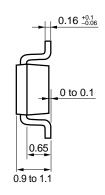
 $R_{DS(on)2} = 5.2 \Omega MAX. (V_{GS} = 4.5 V, I_{D} = 0.25 A)$

 $R_{DS(on)3} = 6.0 \Omega MAX. (V_{GS} = 4 V, I_{D} = 0.25 A)$

- 4.5 V drive available
- Small and surface mount package (SC-96)

PACKAGE DRAWING (Unit: mm)





- 1. Gate
- 2. Source
- 3. Drain

ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
2SK4147-T1B-AT Note	Duna Co (Tia)	Tana 2000 n/mal	SC-96 (Mini Mold Thin Type)
2SK4147-T2B-AT Note	Pure Sn (Tin)	Tape 3000 p/reel	0.011 g TYP.

Note Pb-free (This product does not contain Pb in the external electrode and other parts.)

Marking: XR

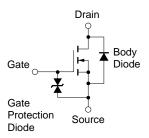
ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	250	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC) (T _A = 25°C)	ID(DC)	±0.5	Α
Drain Current (pulse) Note1	ID(pulse)	±2.0	Α
Total Power Dissipation (T _A = 25°C)	P _{T1}	0.2	W
Total Power Dissipation (T _A = 25°C) Note2	P _{T2}	1.25	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstq	-55 to +150	°C

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Mounted on FR-4 board of 50 mm x 50 mm x 1.6 mm, $t \! \leq \! 5$ sec

EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD.

When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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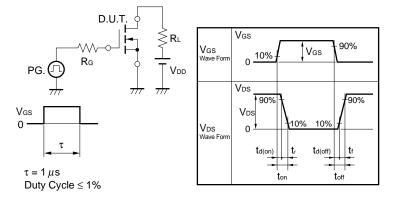


ELECTRICAL CHARACTERISTICS (TA = 25°C)

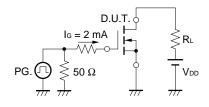
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Inss	V _{DS} = 250 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μΑ
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.0	1.9	2.5	٧
Forward Transfer Admittance Note	y fs	V _{DS} = 10 V, I _D = 0.25 A	0.55			S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = 10 V, I _D = 0.25 A		3.6	4.5	Ω
	R _{DS(on)2}	V _{GS} = 4.5 V, I _D = 0.25 A		3.6	5.2	Ω
	R _{DS(on)3}	V _{GS} = 4 V, I _D = 0.25 A		3.6	6.0	Ω
Input Capacitance	Ciss	V _{DS} = 10 V,		120		pF
Output Capacitance	Coss	V _{GS} = 0 V,		18		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		7		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 125 V, I _D = 0.25 A,		5.5		ns
Rise Time	tr	V _{GS} = 10 V,		6		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		16.5		ns
Fall Time	tf			32		ns
Total Gate Charge	Q _G	V _{DD} = 200 V,		5.5		nC
Gate to Source Charge	Qgs	V _{GS} = 10 V,		1		nC
Gate to Drain Charge	Q _{GD}	l _D = 0.5 A		2		nC
Body Diode Forward Voltage Note	VF(S-D)	I _F = 0.5 A, V _{GS} = 0 V		0.84	1.5	V
Reverse Recovery Time	trr	I _F = 0.5 A, V _{GS} = 0 V,		55		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>μ</i> s		54		nC

Note Pulsed

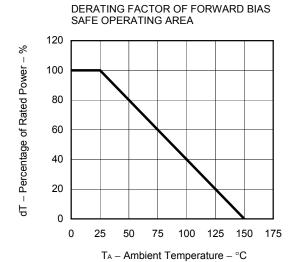
TEST CIRCUIT 1 SWITCHING TIME

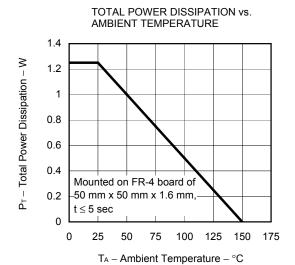


TEST CIRCUIT 2 GATE CHARGE

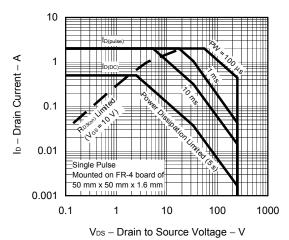


TYPICAL CHARACTERISTICS (TA = 25°C)

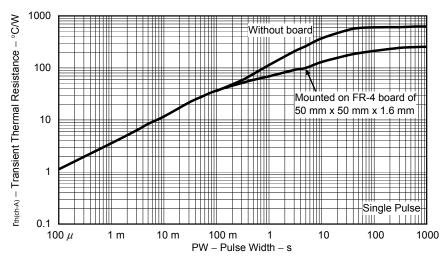




FORWARD BIAS SAFE OPERATING AREA



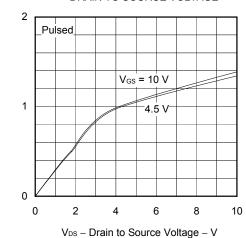
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



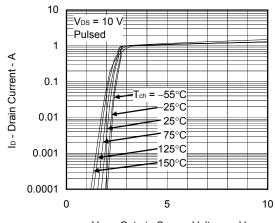
3

Ip - Drain Current - A

DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

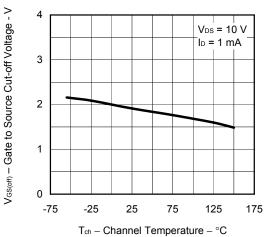


FORWARD TRANSFER CHARACTERISTICS

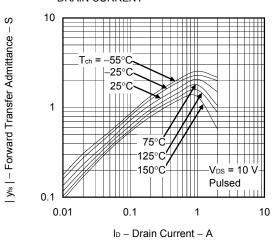


V_{GS} – Gate to Source Voltage – V

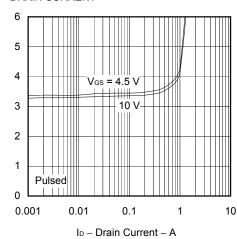
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



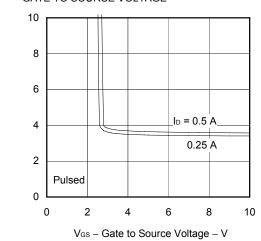
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

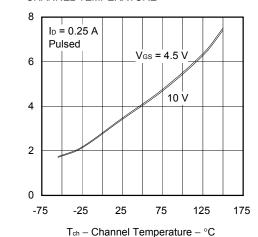


 $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}-\mathsf{Drain}$ to Source On-state Resistance $-\Omega$

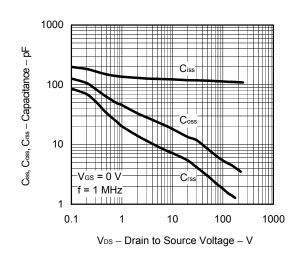
 $\mathsf{R}_{\mathsf{DS}(m)}-\mathsf{Drain}$ to Source On-state Resistance $-\Omega$

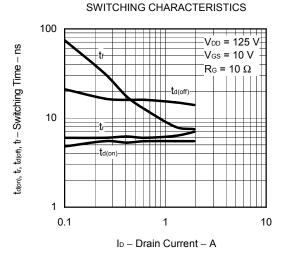
 $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}-\mathsf{Drain}$ to Source On-state Resistance $-\Omega$

DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE

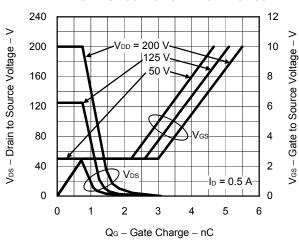


CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

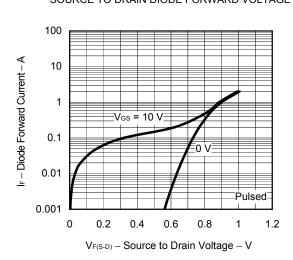




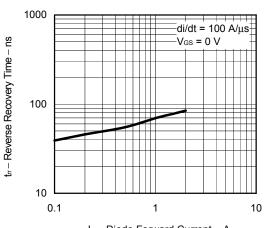
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



IF - Diode Forward Current - A

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